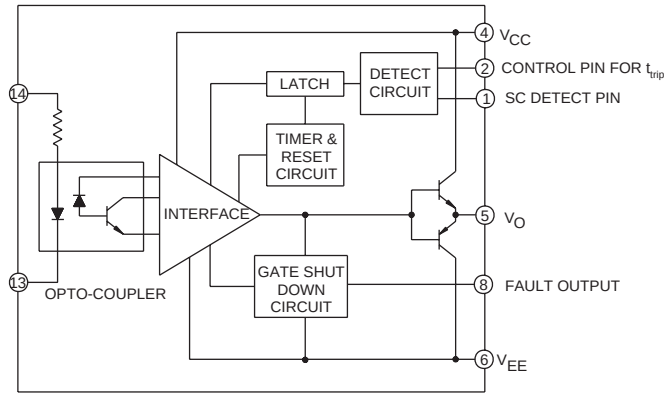
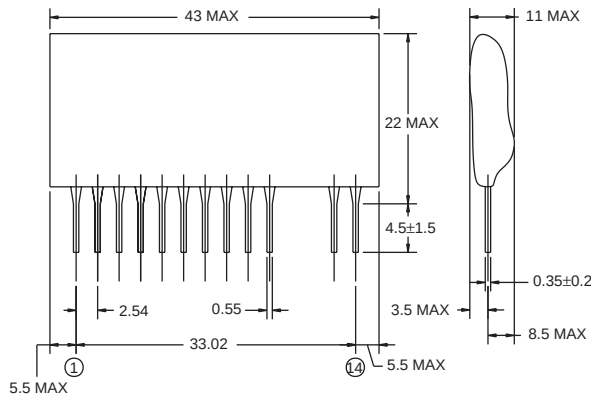


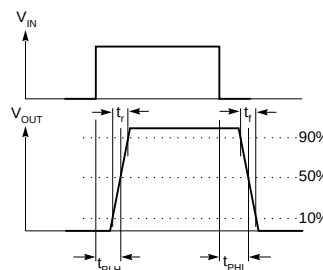
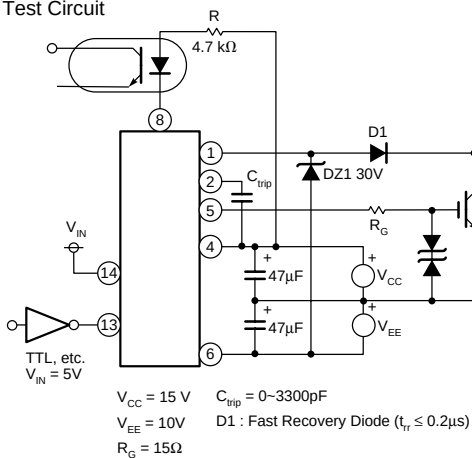
Block Diagram



Outline Drawing



Test Circuit



Hybrid Integrated Circuit For Driving IGBT Modules

Description:

M57159L-01 is a hybrid integrated circuit designed for driving n-channel IGBT modules in any gate amplifier application. This device operates as an isolation amplifier for these modules and provides the required electrical isolation between the input and output with an opto-coupler. Short circuit protection is provided by a built in desaturation detector. A fault signal is provided if the short circuit protection is activated.

Features:

- ☐ Electrical Isolation between input and output with opto-couplers.
($V_{iso} = 2500V_{RMS}$ for 1 min.)
- ☐ Two supply drive topology
- ☐ Built in short circuit protection circuit with a pin for fault output
- ☐ TTL compatible input interface

Application:

To drive IGBT modules for inverter, AC Servo systems, UPS, CVCF inverter, and welding applications.

Recommended Modules:

$V_{CES} = 600\text{V Series}$
(up to 150A Class)

$V_{CES} = 1200\text{V Series}$
(up to 75A Class)



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

M57159L-01

Hybrid IC for IGBT Gate Driver

Absolute Maximum Ratings, $T_a = 25^\circ\text{C}$ unless otherwise specified

Item	Symbol	Test Conditions	Limit	Units
Supply Voltage	V_{CC}	DC	18	Volts
	V_{EE}	DC	-12	Volts
Input Voltage	V_I	Applied between: (13) – (14)	-1 ~ 7	Volts
Output Voltage	V_O	Output Voltage "H"	V_{CC}	Volts
Output Current	I_{OHP}	Pulse Width 2 μ s, $f \leq 20\text{kHz}$	-1.5	Amperes
	I_{OLP}	Pulse Width 2 μ s, $f \leq 20\text{kHz}$	1.5	Amperes
Isolation Voltage	V_{RMS}	Sinewave Voltage 60Hz, 1 min.	2500	Volts
Case Temperature	T_c		85	$^\circ\text{C}$
Operating Temperature	T_{opg}		-20 ~ 60	$^\circ\text{C}$
Storage Temperature	t_{stg}		-25 ~ 100	$^\circ\text{C}$
Fault Output Current	I_{FO}	Applied (8) pin	20	mA
Input Voltage	V_{R1}	Applied (1) pin	50	Volts

M57159L-01

Hybrid IC for IGBT Gate Driver

Electrical Characteristics, $T_a = 25^\circ\text{C}$, $V_{CC} = 15\text{V}$, $V_{EE} = -10\text{V}$ unless otherwise specified

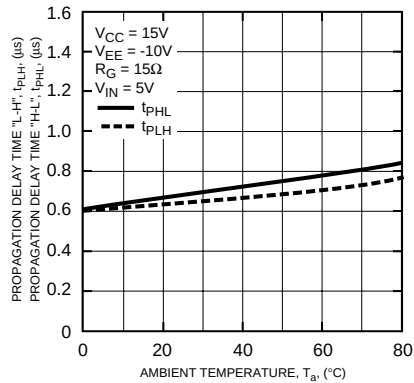
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Supply Voltage	V_{CC}	Recommended Range	14	15	—	Volts
	V_{EE}	Recommended Range	-7	—	-10	Volts
Pull-up Voltage on Input Side	V_{IN}	Recommended Range	4.75	5.00	5.25	Volts
"H" Input Current	I_{IH}	Recommended Range	15.2	16	19	mA
Switching Frequency	f	Recommended Range	—	—	20	kHz
Gate Resistor	R_G	Recommended Range	4.2	—	—	Ω
"H" Input Current	I_{IH}	$V_{IN} = 5\text{V}$	—	16	—	mA
"H" Output Voltage	V_{OH}		13	14	—	Volts
"L" Output Voltage	V_{OL}		-8	-9	—	Volts
"L-H" Propagation Time	t_{PLH}	$I_{IH} = 16\text{mA}$	—	0.7	1.3	μs
"L-H" Rise Time	t_r	$I_{IH} = 16\text{mA}$	—	0.8	1.5	μs
"H-L" Propagation Time	t_{PHL}	$I_{IH} = 16\text{mA}$	—	0.7	1.3	μs
"H-L" Fall Time	t_f	$I_{IH} = 16\text{mA}$	—	0.3	0.6	μs
Timer	t_{timer}	Between start and cancel (under input sign "L")	1.0	—	2.0	ms
Fault Output Current	I_{FO}	Applied ⑧ pin, $R = 4.7\text{k}\Omega$	—	5.0	—	mA
Controlled Time Detect Short Circuit 1	t_{trip1}	Pin ①: 15V and more, Pin ②: Open	—	2.4	—	μs
Controlled Time Detect Short Circuit 2*	t_{trip2}	Pin ①: 15V and more, Pin ②-④: 1000pF (Connective Capacitance)	—	2.8	—	μs
SC Voltage	V_{SC}	SC Detect Voltage	15	—	—	Volts

*Length of wiring of capacitor controlled time detect short circuit is within 5cm from ② and ④ pin coming and going.

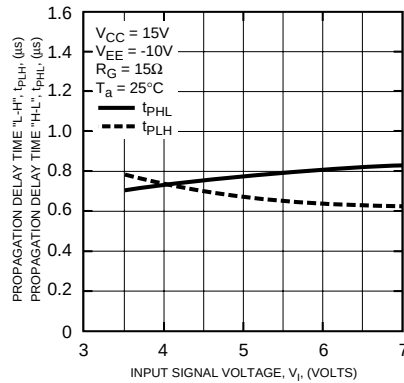
M57159L-01

Hybrid IC for IGBT Gate Driver

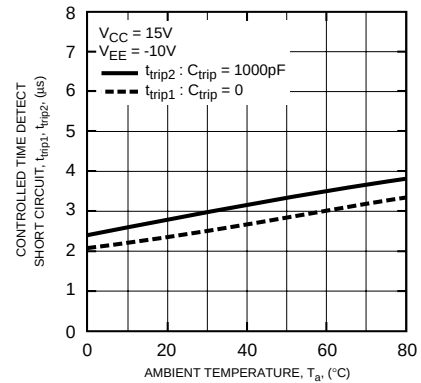
PROPAGATION DELAY TIME
VS. AMBIENT TEMPERATURE
CHARACTERISTICS (TYPICAL)



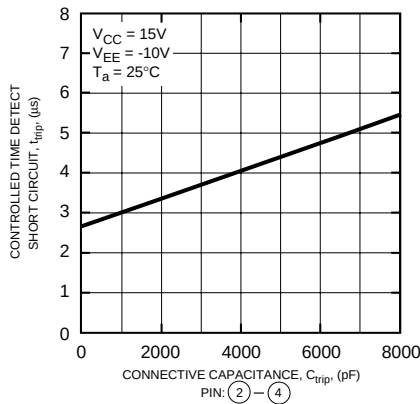
PROPAGATION DELAY TIME
VS. SIGNAL VOLTAGE
CHARACTERISTICS (TYPICAL)



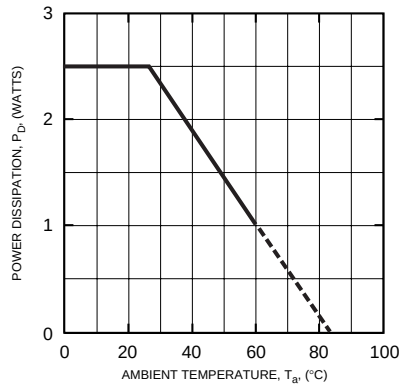
CONTROLLED TIME DETECT
VS. AMBIENT TEMPERATURE
CHARACTERISTICS (TYPICAL)



CONTROLLED TIME DETECT
VS. CONNECTIVE CAPACITANCE
CHARACTERISTICS (TYPICAL)



POWER DISSIPATION
VS. AMBIENT TEMPERATURE
(MAXIMUM RATING)



DISSIPATION CURRENT
VS. SUPPLY VOLTAGE
INPUT SIGNAL "L" (TYPICAL)

